Superconductivity Fluctuations in a One-dimensional Two Band Electron-Phonon Model with Strong Repulsive Interactions.

S.I.Matveenko[+]*, A.R.Bishop* and A.Balatsky*[+]
[+] *Landau Institute for Theoretical Physics, Moscow, Kosygina str., 2, Russia, 117940*
**Theoretical Division, Los Alamos National Laboratory, Los Alamos, New Mexico 87545, USA*
(April 25, 1995)

We study a one-dimensional, two band model with short range electron-electron repulsions (onsite U and nearest-neighbour V terms) and electron-phonon coupling. We show that there is a region of U,V and band filling in which singlet superconductivity fluctuations are dominant. This region is absent without electron-phonon interactions and includes large values of U,V.
PACS numbers: 71.30 + h, 74.10 + v, 74.20 - z

arXiv:cond-mat/9505032v2 9 May 1995

The physics of low dimensional strongly correlated fermion systems with repulsive interactions is a topic of active interest, largely due to the absence of a clear understanding of the origin of high-T_c superconductivity in cuprate oxides and the role of phonons in these correlated systems. In the framework of a simple one-dimensional (1-d) Cu-O chain model [1], we investigate the effects of both short range electron-electron (e-e) repulsive interactions (onsite U and nearest neighbour Cu-O repulsion V) and electron-phonon (e-p) coupling on the ground state of the system. We show that superconducting (SC) correlations are absent in the model if we take into account e-e interactions only. The inclusion of e-p interactions leads to the appearance of a region of (U, V,ρ) (ρ, the band - filling) in which superconducting fluctuations are dominant. On the other hand the ground state of the system in the absence of e-e repulsion is a charge-density -wave (or spin-density-wave) state without a divergent SC response. Thus, the origin of the region with dominant SC response is the *combined* effect of e-e and e-p interactions for this model.

We use a renormalization group (RG) two cut-off approach, developed in earlier works [2,3]. With some assumptions on the model parameters our analysis is valid in the large U, V limit. The possibility of superconducting fluctuations in quasi-1-d systems with strong repulsive e-e interactions and e-p coupling was first raised in work of Zimanyi et.al. [3], where results are obtained for a massive Thirring model. The two-band model without e-p interactions was considered in [1], where numerical results are presented, pointing out the existence of SC fluctuations in a strong coupling limit.

We consider a chain consisting of two types of atoms: Cu on odd sites with d-orbitals and O on even lattice sites with p-orbitals. The Hamiltonian of the system is

$$H = H_0 + H_{ee} + H_{ep} \tag{1}$$

$$H_0 = -t \sum_{<i,j>} c^+_{p,i} c_{d,j} + h.c. + \sum_i \Delta (c^+_{p,i} c_{p,i} - c^+_{d,i} c_{d,i}) \tag{2}$$

$$H_{ee} = \sum_{\alpha=d,p} \sum_i U_\alpha c^+_{\alpha,i,\uparrow} c_{\alpha,i,\uparrow} c^+_{\alpha,i,\downarrow} c_{\alpha,i,\downarrow} + V \sum_{<i,j>} c^+_{d,i} c_{d,i} c^+_{p,j} c_{p,j}, \tag{3}$$

where t is the hopping integral, $< i,j >$ are nearest-neighbour sites, $\Delta = (E_p - E_d)/2$, E_p and E_d are site energies, U_d, U_p are Hubbard onsite repulsive energies, and V is the repulsion amplitude between nearest neighbour sites. Direct antiferromagnetic coupling betveen Cu sites is omitted. Also

$$H_{ep} = H_{ep,1} + H_{ep,2}, \tag{4}$$

and we consider two models of electron-phonon coupling: the molecular crystal (MC) model with the Hamiltonian $H_{ep,1}$ in which optical phonons couple to the electron site energy; and the Su-Schrieffer-Heeger (SSH) model with the Hamiltonian $H_{ep,2}$ in which the lattice distortions modulate the electron-hopping matrix element t. The Hamiltonian $H_{ep,1}$ consists of two parts $H_{ep,1} = H_{ep,d} + H_{ep,p}$, where the each part has the form

$$H_{ep} = \sum \frac{P_i^2}{2M} + \frac{1}{2}\kappa q_i^2 + \lambda q_i \rho_i = \sum \omega_0 (d_k^+ d_k + \frac{1}{2}) + \frac{g}{N^{1/2}} (d_k + d_k^+) \rho_k, \tag{5}$$

with $\omega_0 = (\kappa/M)^{1/2}$, $g = \lambda/(2M\omega_0)^{1/2}$, $\rho_k = \sum c^+_{k+q} c_q$. ($M$ ion mass, ω_0 optic phonon frequency, κ elasticity constant, λ e-p coupling constant.) All terms in (5) have indices d or p and the sum is over odd or even sites for $H_{ep,d}$, $H_{ep,p}$ respectively. The Hamiltonian $H_{ep,2}$ takes into account intermolecular phonon modes

$$H_{ep,2} = \sum \frac{P_i^2}{2M} + \frac{1}{2}\kappa (q_{i+1} - q_i)^2 - \sum_{<i,j>} \delta t_{i,j} c^+_{d,i} c_{p,j} = \sum \omega_k (f_k^+ f_k + \frac{1}{2}) + \frac{1}{N^{1/2}} \sum g(k,q) (f_q + f^+_{-q}) c^+_{d,k+q} c_{p,k}, \tag{6}$$

where $\delta t_{i,j} = \lambda (q_i - q_j)$, $\omega_q = 2(\kappa/M)^{1/2} \sin(qa/2)$ is the acoustic phonon frequency,

$g(k,q) = i4\lambda \sin(qa/2)\cos(ka+qa/2)/(2M\omega_q)^{1/2}$, and a is the Cu-O lattice constant.

First we consider the noninteracting Hamiltonian H_0. Diagonalization gives

$$H_0 = \sqrt{4t^2\cos^2 ka + \Delta^2}(c_2^+(k)c_2(k) - c_1(k)^+c_1(k)), \tag{7}$$

where

$$\begin{aligned} c_d(k) &= \cos\theta_k c_1(k) + \sin\theta_k c_2(k) \\ c_p(k) &= -\sin\theta_k c_1(k) + \cos\theta_k c_2(k) \end{aligned} \tag{8}$$

with $\tan(2\theta_k) = -2t\cos(ka)/\Delta$, $-\pi/2 < 2\theta_k < \pi/2$. We now have a 2-band electronic structure and consider the case of an entirely filled lower band. The filling factor of the upper band is $0 < \rho < 2$ (empty for $\rho = 0$ and filled for $\rho = 2$). With unit cell $2a$, the quasimomentums k and $k + \pi/a$ are equivalent, and we may consider that states in the lower band have quasimomenta in the interval $-\pi/2a < k < \pi/2a$ and in the upper band $\pi/2a < |k| < \pi/a$; then $k_F a = \pi/2 + \pi\rho/4$. The Fermi velocity is

$$v_F = -\frac{2at\sin(2k_F a)}{\sqrt{4t^2\cos^2(k_F a) + \Delta^2}}. \tag{9}$$

Since we will use an RG approach we take into account only states in the upper band in the vicinity of E_F which are described by operators c_2. Then H_0 has the form, in x-representation,

$$H_0 = v_F\Psi_{2,+}^+(-i\frac{\partial}{\partial x})\Psi_{2,+} + v_F\Psi_{2,-}^+(i\frac{\partial}{\partial x})\Psi_{2,-}, \tag{10}$$

where $\Psi_{2,\pm}$ includes momenta near $\pm k_F$, respectively. Below we will omit the index 2 and also terms in H comprising Ψ_1 (taking into account terms with Ψ_1 can produce a shift of the chemical potential and some renormalization of the Fermi velocity.) Therefore we can substitute in the Hamiltonian terms

$$\Psi_d \to \sin\theta_F\Psi(x),\ \Psi_p \to \cos\theta_F\Psi(x). \tag{11}$$

Note that in the cases $t/\Delta \ll 1$ or $\rho \ll 1$ we have

$$\sin\theta_F \approx \theta_F \approx \frac{t\sin(\pi\rho/4)}{\Delta}. \tag{12}$$

We first consider e-e interaction effects. For the Cu-O case it is appropriate to consider $U_d \gg U_p$. We first study the case $U_p = 0$. The effect of small U_p is easily taken into account and will be discussed below. In terms of a "g-ology" model [4] the Hamiltonian H_{ee} gives the scattering amplitudes

$$\begin{aligned} g_1 &= \frac{Ua}{2}\sin^4\theta_F + 2Va\sin^2\theta_F\cos(2k_F a) = g_3 \\ g_2 &= \frac{Ua}{2}\sin^4\theta_F + 2Va\sin^2\theta_F = g_4, \end{aligned} \tag{13}$$

where g_1 is the back scattering amplitude, and g_2, g_4 are forward scattering. The "Umklapp" part g_3 exists only for the half filled case $\rho = 1$: for the sake of simplicity we will not consider this case. Since we use a RG approach below, we consider $g_i/\pi v_F \le 1$, that is $Ua, Va \le \pi v_F$ or $\sin\theta \ll 1$ for large U, V. We have spin - rotation invariance, i.e., $g_\perp = g_\parallel$. Therefore, if it is not essential we are omitting spin indices. The effect of the g_4 term is taken into account separately: it simply produces a shift in the velocity of the spin and charge degrees of freedom: $v_\sigma = v_F(1+g_4),\ v_\rho = v_F(1-g_4)$

The usual RG equations defining the scaling behaviour of the system are [4]

$$g_1' = \frac{1}{\pi v_\sigma}g_1^2 \tag{14}$$

$$g_c \equiv g_1 - 2g_2 = const. \tag{15}$$

For $g_1 \ge 0$ the excitation spectrum is gapless $g_1 \to g_1^* = 0$, and there is a gap if $g_1 < 0$. The charge excitation spectrum is gapless if $g_c \ge 0$ and has a gap Δ_ρ if $g_c < 0$. The ground state has a most divergent singlet (triplet) superconductivity (SC) response when $g_c \ge 0, g_1 < 0$ ($g_c \ge 0, g_1 \ge 0$). In our case

$$g_c = -\frac{Ua}{2}\sin^4\theta_F + 2Va\sin^2\theta_F\cos^2\theta_F(\cos(2k_F) - 2) < 0. \tag{16}$$

Therefore there is no region (U, V) with divergent SC fluctuations. Possible ground states are charge- or spin-density wave, depending on the sign g_1. (This sign can vary due to the $\cos k_F a$ term). We see that in order to obtain SC correlations it is necessary to have large positive g_1^* or negative g_2^* terms. As we will see below this condition can be achieved by taking into account e-p interactions.

Second order perturbation theory in e-p interaction produces a retarded e-e interaction [2] for ω less than a Debye frequency $\omega < \omega_D \sim (\kappa/M)^{1/2}$. (We consider the case $\omega_D < E_F$). The effective e-e interaction can be described in "g-ology" terminology: $g_{1,ph} = -2g^2(k_F, 2k_F)/\omega_{2k_F}$, $g_{2,ph} = -2g^2(k_F, 0)/\omega_0$, $g_{3,ph} = g_{1,ph}$ (half-filled band only). In the case of the MC model (5)

$$g_{1,ph} = g_{2,ph} = g_{3,ph} = -\frac{\lambda^2}{4\kappa}, \tag{17}$$

whereas the SSH model (6) gives

$$g_{1,ph} = g_{3,ph} = -4\frac{\lambda^2}{\kappa}(\sin^2\theta_F\cos^2\theta_F). \tag{18}$$

The parameters κ, λ in (17), (18) are, of course, different, as well as other similar parameters in Hamiltonians

$H_{ep,1}$, $H_{ep,2}$. Note that all terms are negative, and $g_{2'ph}$ is due solely to onsite e-p coupling and does not contain renormalization terms $\sin\theta_F$, $\cos\theta_F$. In the case $\theta \ll 1$ the onsite e-p interaction is dominant. We now have two types of e-e interactions with cutoffs E_F and ω_D. We thus use the RG procedure [2,3] for a two cut-off model. The one-loop scaling equations (14),(15) for the g_i are unaffected by the presence of retarded interactions. The equations for the $g_{i,ph}$, taking into account cross terms $g_i g_{j,ph}$, were derived in [3]:

$$g'_{1,ph} = \frac{1}{\pi v_F}(\frac{3}{2}g_1 + \frac{1}{2}g_c + g_{1,ph})g_{1,ph} \tag{19}$$

$$g'_{2,ph} = 0. \tag{20}$$

We will consider the case $g_{3,ph} = 0$. The integration in (19),(20) is taken from E_F to $\omega_0 \sim \omega_D(\omega_0)$, where $\omega_D(\omega_0)$ is the renormalized value of ω_D [3]. As a result the combined action of different scattering processes is described by

$$g_i^T = g_i^* + g_{i,ph}^*. \tag{21}$$

The properties of the system at energies small compared to ω_0 are derived from a model with single interactions g_i^T and bandwith ω_0.

We now examine the solutions of equations (14), (15), (19), (20). The initial conditions for (14),(15) are defined by (13). The initial conditions for (19),(20) are defined by (17),(18). We denote $g_{1,ph}^{(0)} = -\gamma$, $g_{2,ph}^{(0)} = -\tilde{\gamma}$. If $g_1^{(0)} \geq 0$ (we will see that this is the situation in the interesting region), from (12) we obtain that g_1 scales toward small positive values $g_1^* \ll g_1^{(0)}$. Note that in the case $\theta \ll 1$ we have $g_{1,ph}^{(0)} \approx g_{2,ph}^{(0)}$, that is $\tilde{\gamma} \approx \gamma$. From (13) it follows that $g_1^* - 2g_2^* = g_1^{(0)} - 2g_{(2)}^0$. A positive derivative in (19) implies that $g_{1,ph}$ scales toward large negative values. We consider the opposite case $g'_{1,ph} < 0$. Then, at least initially, $g_{1,ph}$ will scale toward a small negative value. Therefore we demand that

$$\frac{3}{2}g_1^{(0)} + \frac{1}{2}g_c^{(0)} + g_{1,ph}^{(0)} > 0, \tag{22}$$

since $g_{1,ph} < 0$. The inequality (22) can not be valid throughout the scaling process, since g_1 scales to small values. Therefore the value $g_{1,ph}^*$ may not be very small. We do not require $|g_{1,ph}^*| \ll \gamma$; for our purposes it is sufficient that $g_{1,ph}^* > \gamma - 2\tilde{\gamma}$, as we show below. The value $g_{2,ph}$ is not scaled as follows from (20), i.e., $g_{2,ph}^* = -\tilde{\gamma}$. This value does not contain the renormalization coefficient $\sin\theta_F$. As a result of scaling we have the state with $g_i^T = g_i^* + g_{i,ph}^*$. The ground state of the system with the new scaling amplitudes has dominant divergent SC susceptibility if

$$g_c^T = g_1^T - 2g_2^T = g_1^{(0)} - 2g_2^{(0)} + g_{1,ph}^* + 2\tilde{\gamma} > 0. \tag{23}$$

Since we suppose that $g_{1,ph}^T \approx g_{1,ph}^* < 0$, we have a state with spin gap Δ_σ. Therefore the dominant singularity is the singlet SC response with SC correlation function

$$R(x) \sim x^{-\frac{1}{K_\rho}},\ K_\rho = \sqrt{\frac{1 + g_c^T/2\pi v_\rho}{1 - g_c^T/2\pi v_\rho}} > 1. \tag{24}$$

In this case the CDW response can be divergent with correlation function $\propto x^{-K_\rho}$. The inequalities (22),(23) define the region in which singlet SC correlations are dominant. In terms of $u = \frac{Ua}{2}\sin^4\theta$, $v = Va\sin^2\theta\cos^2\theta$ we rewrite (22),(23) as

$$\gamma + 2v(1 + 2\cos(\frac{\pi\rho}{2})) < u < 2\gamma^* - 2v(2 + \cos(\frac{\pi\rho}{2}), \tag{25}$$

where $2\gamma^* = 2\tilde{\gamma} + g_{1,ph}^*$. It is easy to obtain the solution of (25). This is the region $ABCD$ in Fig.1 delineated by lines: $u = 0, v = 0, u = \gamma - 2v$, $u = 2\tilde{\gamma} + g_{1,ph}^* - 2v$.

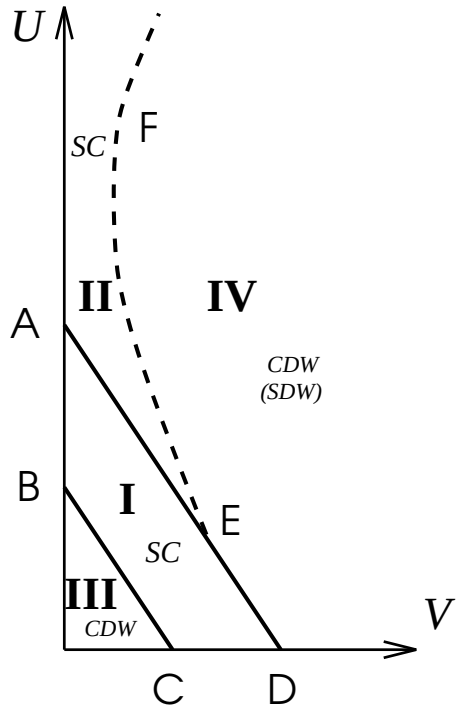

FIG. 1. Phase diagram obtained by two cut-off RG scaling. Divergent SC response regions are I and II.

Recall that in the case $\theta \ll 1$, Eq.(12), the bare repulsive energies $U \sim u/\theta^4, V \sim v/\theta^2 \gg \gamma$. Thus our model includes the case of strong electron repulsion. For any point (u, v) in the region ABCD (25) is valid for

$$\rho > \frac{2}{\pi}\cos^{-1}(max\{\frac{u - \gamma - 2v}{4v},\ \frac{2\gamma^* - 4v - u}{2v}\}, \tag{26}$$

In the case $t/\Delta \ll 1$ we can obtain the phase diagram in term of the bare values U, V. Then the coordinates of points A, B, C, D are $A = \{0, (4\gamma^*)(\Delta/t)^4\}$, $B = \{0, 2\gamma(\Delta/t)^4\}$, $C = \{(\gamma/2)(\Delta/t)^2, 0\}$, $D = \{(\gamma^*/2)(\Delta/t)^2, 0\}$. The SC region is deformed to include region II due to the $\sin(\pi\rho/4)$ term. The equation of the curve EF is

$$V = \frac{\Delta^2}{t^2}\frac{((2\gamma^* - \gamma)k + 4\gamma + 16\gamma^*)^2}{72(k+2)(\gamma + 2\gamma^*)},\ U = 2kV\frac{\Delta^2}{t^2}. \quad (27)$$

In the limit $k \to \infty$ we have $U \propto V^2$, but in this region $\rho \sim 1/U^{1/4} \to 0$. The inequality (25) with $t/\Delta \ll 1$ becomes

$$\begin{aligned}(U_1 + 8V_1)y^2 - 6V_1 y - \gamma > 0,\\ (4V_1 - U)y^2 - 6V_1 y + 2\gamma^* > 0,\end{aligned} \quad (28)$$

where $V_1 = V(\Delta/t)^2, U_1 = \frac{U}{2}(\Delta/t)^4$, $y = \sin^2(\pi\rho/4)$. In region I the solution of (28) is $\rho_0 < \rho < 2$, where $\sin^2(\pi\rho_0/4) = y_0$ is the largest root of eqn. (28). In the region II we have $\rho_1(U, V) < \rho < \rho_2(U, V)$, where ρ_1, ρ_2 are easy obtained from (28). If $V = 0$ the solution is

$$\frac{4}{\pi}\sin^{-1}\left(\frac{\gamma}{U_1}\right)^{1/4} < \rho < \frac{4}{\pi}\sin^{-1}\left(\frac{2\gamma^*}{U_1}\right)^{1/4} \quad (29)$$

for $U_1 > \gamma$; if $U = 0$, then in the region $\gamma/2 < V_1 < \gamma^*$ the solution is $\sin^2(\pi\rho/4) > y_0$, where y_0 is the largest root of eqn. (28) for $U = 0$.

In using the RG approach, we supposed as usual that $g_i/\pi v_F < 1$. For small t/Δ we have the initial value $v_F^{(0)} \sim (t/\Delta)\sin(\pi\rho/2)$. Recalling that $g_i \sim (t\sin(\pi\rho/4)/\Delta)^2$ or $(t\sin(\pi\rho/4)/\Delta)^4$, $g_{2,ph} = const$, we suppose that our results are reasonable if we are not too close to band edges, that is $\epsilon_1 < \rho < 2 - \epsilon_2$, and $\rho \neq 1$ ($g_3 = 0$). It follows from our analysis that in region III we have large spin and charge gaps, so that there is only a charge-density-wave divergent response. In the region IV we have $g_c^T < 0$, small $g_1^T < 0$ and thus divergent charge- and spin-density-wave (if $g_1^* \to 0$) responses.

In our consideration above we have not taken into account effects of U_p repulsion. This is easily achieved by substituting u into (20) in the form $u = (Ua\sin^4\theta_F + U_p a\cos^4\theta_F)/2$. For small values of U_p, the RG approach remains valid, and all results in terms of the new u, v are retained. For $t/\Delta \ll 1$ we have $\cos\theta_F \sim 1$, so that we can not consider the large U_p limit in our approach.

In conclusion, using a two cutoff RG approach we have studied a two band, 1-d tight-binding model with e-e and e-p interactions. We included onsite U and nearest neighbour V electron repulsions, as well as intra- and inter-molecular e-p coupling. We have shown that there is no U, V, ρ, t, Δ parameter region with dominant divergent SC response in the absence of e-p interactions. In the lowest order RG approach we found that such a region *does* occur if we include e-p coupling with optical intra-molecular modes. Only this form of e-p interaction produces an effective renormalized $g_{2,ph}$ term. We have found that the singlet SC region includes large values of the U, V repulsive interactions if $t\sin(\pi\rho/4)/\Delta \ll 1$. Note that this behavior is impossible in the framework of a one-band model, for which $\Delta = 0$. Then, instead of (25) we have

$$\gamma + 2V(1 - 2\cos(\pi\rho)) < U < 2\tilde{\gamma} + g_{1,ph}^* - 2V(2 - \cos(\pi\rho), \quad (30)$$

where $\gamma = -g_{1,ph}^{(0)}$, $\tilde{\gamma} = -g_{2,ph}^{(0)}$, $0 < \rho < 2$. The solution of (30) is the same region ABCD in Fig.1, provided $2\tilde{\gamma} + g_{1,ph}^* > \gamma$. However the bare values U, V must be very small, of the order of phonon scattering strengths. Moreover, in this case the requirement $2\tilde{\gamma} + g_{1,ph}^* > \gamma$ can be not realized. (Recall that in the two band case we have $\gamma \sim \tilde{\gamma}$ in the limit $t/d \ll 1$, since effective intersite phonon coupling terms are small due to the factor $(t/\Delta)^2$). Note also that we have used a RG approach. Therefore we did not consider the strong coupling limit where a phase separation instability could take place [1]: our results are valid in some vicinity of the SC fluctuation phase.

We have proposed one possible scenario for the origin of dominant SC fluctuations in quasi-one-dimensional systems as a result of the combined effect of repulsive e-e and attractive e-p interactions in a 2-band situation. We suggest that features of this picture will survive in analogous two-dimensional models of high-T_c superconductors [5], in particular in 3-band Peierls-Hubbard models. However the orbital structure of the order parameter in this case (s-wave vs d-wave) is unclear without detailed calculations.

One of us (S.M) wishes to thank Los Alamos National Laboratory for support and hospitality. Work at Los Alamos is performed under the auspices of the U.S.D.o.E.

[1] C.M.Varma, S.Schmitt-Rink and E.Abrahams, Solid State Commun. **62**, 681 (1987); A.Sudbø, S.Schmitt-Rink, C.M.Varma, Phys.Rev. **B46**, 5548 (1992); A.Sudbø, C.M.Varma, T.Giamarchi, E.B.Stechel and R.T.Scalettar, Phys.Rev.Lett. **70**, 978 (1993).

[2] L.G.Caron and C.Bourbonnuis, Phys.Rev.**B29**, 4230 (1984); G.S.Grest, E.Abrahams, S.-T.Chui, P.A.Lee and A.Zawadowski, Phys.Rev. **B14**,1225 (1976).

[3] G.T.Zimanyi, S.A.Kivelson and A.Luther, Phys.Rev.Lett. **60**, 2089 (1988).

[4] J.Solyom Adv. Phys. **28**, 201 (1979).

[5] Z.Tesanovic, A.R.Bishop, R.L.Martin, Solid State Commun. **68**, 337 (1988).